NSN 5962-01-283-9150

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-283-9150

Body Length:
Between 1.235 inches and 1.285 inches
Body Width:
Between 0.515 inches and 0.600 inches
Body Height:
Between 0.145 inches and 0.187 inches
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+125.0 degrees celsius
Features Provided:
Electrostatic sensitive and monolithic and programmable and ultraviolet erasable
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line Dual-in-line
Output Logic Form:
Metal oxide-semiconductor logic
Input Circuit Pattern:
14 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
26.5 volts power source
Time Rating Per Chacteristic:
450.00 nanoseconds propagation delay time, low to high level output and 450.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Eprom
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
Yes - demil/mli

Fiig:

A458a0